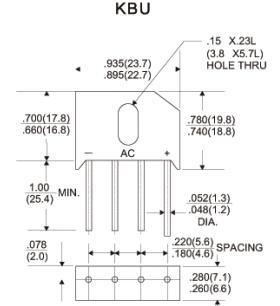


SINGLE-PHASE SILICON BRIDGE RECTIFIERS PBU/KBU10 SERIES 50 to 1000 V 10.0 A

FEATURES

- Ideal for printed circuit board
- Realiable low cost construction utilizing molded plastic technique
- Plastic material has underwriters laboratory Flammability Classification 94V-0
- Surge overload rating:200 amperes peak
- Mounting position: Any
- Mounting Torgue: 5 In. lb. max



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25° C ambient temperature unless otherwise specified. resistive or inductive load, 60HZ. For capacitive load, derate current by 20%.

	Symbols	PBU/KBU 10005	PBU/KBU 1001	PBU/KBU 1002	PBU/KBU 1004	PBU/KBU 1005	PBU/KBU 1006	PBU/KBU 1007	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	60	100	200	400	600	800	1000	Volts
	V _(AV)	10							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	240							Amp
Maximum Instantaneous Forward Voltage Drop Per Element at 5.0A	VF	1.1							Volts
Maximum DC Reverse Current at rated @ T_A =25°C DC Blocking Voltage Per Element @ T_A =100°C	I _R	10 100							μ Amp
Operating Temperature Range	T_{J}	-65 to +150							$^{\circ}$
Storage Temperature Range	T _{STG}	-65 to +150							$^{\circ}$

Notes:

1. Thermal Resistance Junction to Case per diode.



SINGLE-PHASE SILICON BRIDGE RECTIFIERS PBU/KBU10 SERIES 50 to 1000 V 10.0 A

RATINGS AND CHARACTERISTIC CURVES (PBU10 SERIES)

Fig.1 - DERATING CURVE
OUTPUT RECTIFIED CURRENT

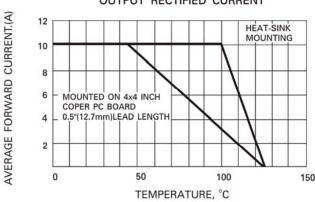


Fig.2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

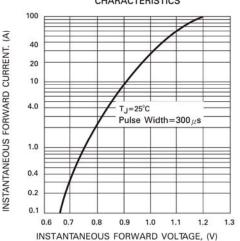


FIG. 3 TYPICAL REVERSE CHARACTERISTICS

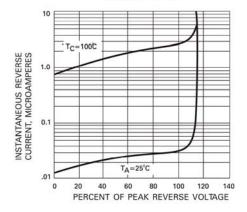


Fig.4 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

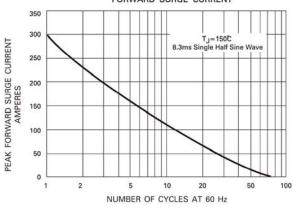


Fig.5 - TYPICAL JUNCTION CAPACITAN(
PER ELEMENT

